NSN 5961-00-137-7421

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View Online at https://aerobasegroup.com/nsn/5961-00-137-7421
Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
1.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-18
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage
static, collector open
Current Rating Per Characteristic:
500.00 milliamperes source cutoff current
Power Rating Per Characteristic:
1.8 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-prf-19500/182 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in
specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on
certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
92220-t067-509 manufacturers specification control
Shelf Life:
N/a
Unit Of Mogeure:

NZ

Demilitarization:

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Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.